NSN 5961-01-458-1729

Diode Semiconductor Device - Page 1 of 1



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Function For Which Designed:	
Switching	
End Application:	
Apx-100	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
200.0 breakdown voltage, dc	
Capacitance Rating In Picofarads:	
0.5	
Maximum Operating Tempurature Per Measurement Point:	
150.0 degrees celsius ambient air	
Test Data Document:	
06845-4060212 drawing (this is the basic governing drawing, such as a contractor drawing, origin	nal equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic govern	ing drawing)
Shelf Life:	
N/a	
Unit Of Measure:	
	
Demilitarization:	
No	
Fiig:	
A110a0	